NSN 5961-01-031-1209

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-031-1209 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Field effect **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 drain to gate voltage and -10.0 gate to source threshold voltage **Current Rating Per Characteristic:** 50.00 milliamperes gate current and 150.00 milliamperes off-state current, dc **Power Rating Per Characteristic:** 1.8 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 10001-2887389 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No